

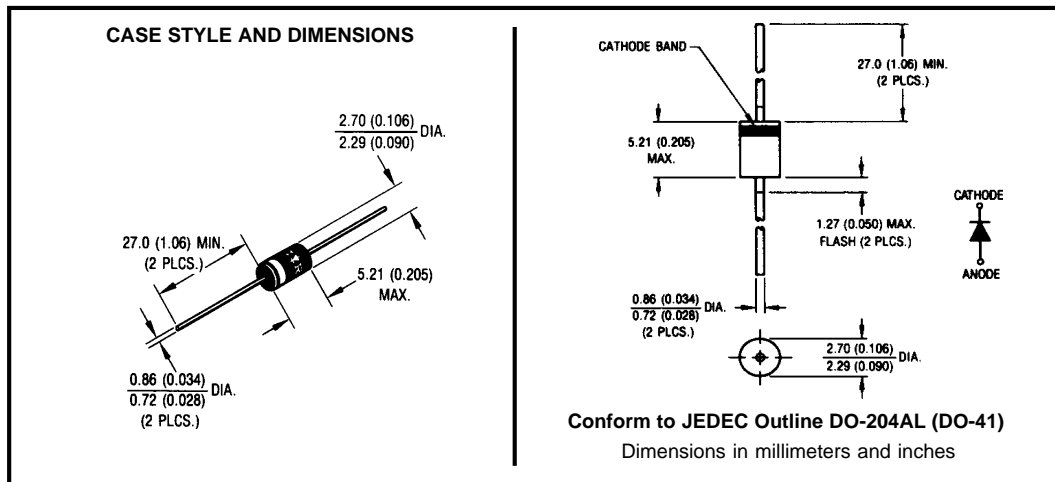
Major Ratings and Characteristics

Characteristics	MBR150 MBR160	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	50/60	V
I_{FSM} @ $t_p = 5 \mu s$ sine	150	A
V_F @ 1 Apk, $T_J = 125^\circ C$	0.65	V
T_J range	-40 to 150	$^\circ C$

Description/ Features

The MBR150, MBR160 axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	MBR150	MBR160
V _R Max. DC Reverse Voltage (V)	50	60
V _{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	Value	Units	Conditions
I _{F(AV)} Max. Average Forward Current * See Fig. 4	1.0	A	50% duty cycle @ T _C = 75°C, rectangular wave form
I _{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	150	A	5µs Sine or 3µs Rect. pulse
	25		10ms Sine or 6ms Rect. pulse
E _{AS} Non-Repetitive Avalanche Energy	2.0	mJ	T _J = 25°C, I _{AS} = 1 Amps, L = 4 mH
I _{AR} Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. V _A = 1.5 x V _R typical

Electrical Specifications

Parameters	Value	Units	Conditions
V _{FM} Max. Forward Voltage Drop * See Fig. 1 (1)	0.75	V	@ 1A
	0.9	V	@ 2A
	1.0	V	@ 3A
	0.65	V	@ 1A
	0.75	V	@ 2A
	0.82	V	@ 3A
I _{RM} Max. Reverse Leakage Current * See Fig. 2 (1)	0.5	mA	T _J = 25°C
	5	mA	T _J = 100°C
	10	mA	T _J = 125°C
C _T Typical Junction Capacitance	55	pF	V _R = 5V _{DC} (test signal range 100Khz to 1Mhz) 25°C
L _S Typical Series Inductance	8.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/µs	(Rated V _R)

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T _J Max. Junction Temperature Range(*)	- 40 to 150	°C	
T _{stg} Max. Storage Temperature Range	- 40 to 150	°C	
R _{thJL} Max. Thermal Resistance Junction to Lead (**)	80	°C/W	DC operation (*See Fig. 4)
wt Approximate Weight	0.33(0.012)	g (oz.)	
Case Style	DO-204AL(DO-41)		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB, Thermal Probe connected to lead 2mm from package

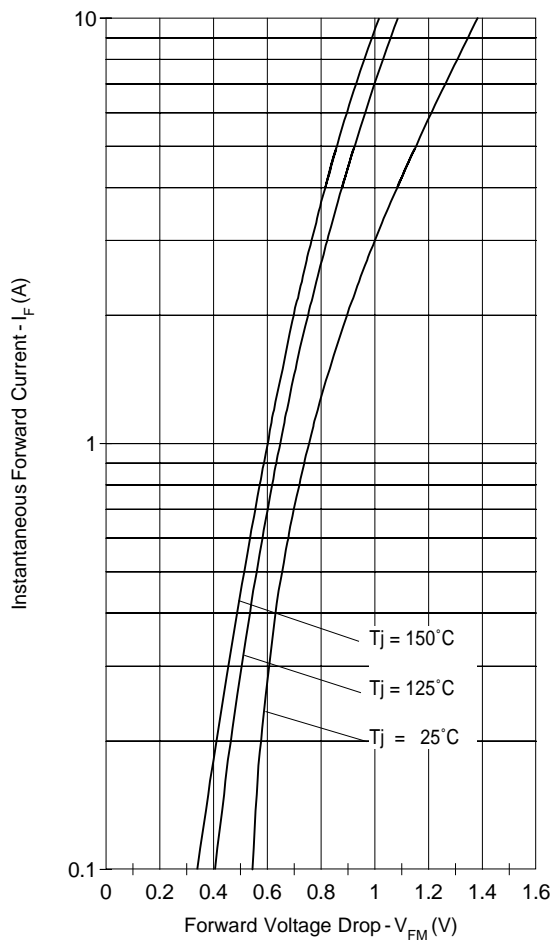


Fig. 1 - Maximum Forward Voltage Drop Characteristics

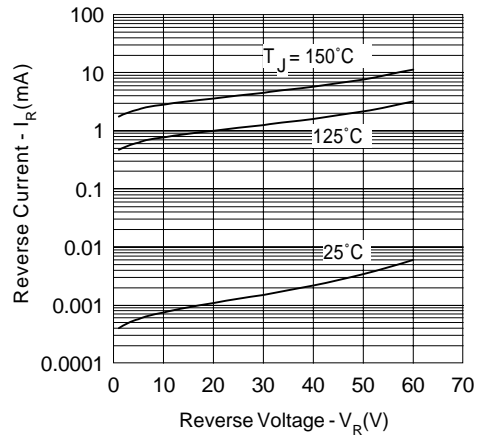


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

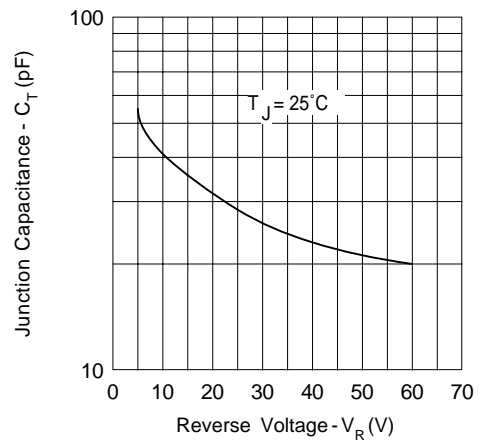


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

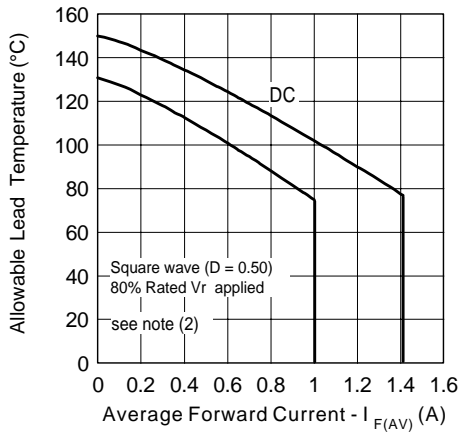


Fig. 4 - Maximum Ambient Temperature Vs. Average Forward Current, Printed Circuit Board Mounted

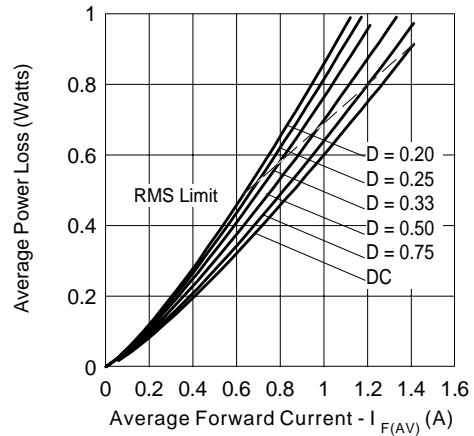


Fig. 5 - Forward Power Loss Characteristics

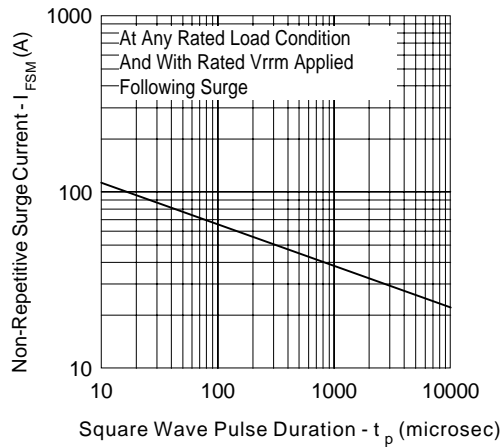


Fig. 6 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6);
 Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

Ordering Information Table

Device Code			
MBR	1	60	TR
①	②	③	④
1	- Schottky MBR Series		
2	- Current Rating: 1 = 1A		
3	- Voltage Rating	60 = 60V	
4	- TR = Tape & Reel package (5000 pcs)	50 = 50V	
	- = Box package (1000 pcs)		

Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.

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